R-16

Code:2305/BL

Faculty of Science

B.Sc (Electronics) I-Year, CBCS-II Semester Backlog Examinations –January, 2021 PAPER: ELECTRONIC DEVICES

Time: 2 Hours Max Marks: 80

I. Answer any Four of the following questions

(4x20=80 Marks)

- Draw a circuit to study the zener diode characteristics. Mention its applications.
- 2. Explain working and uses of a tunnel diode.
- 3. With neat circuit diagram explain input and output characteristics of a PNP transistor. Explain cutoff, active and saturation regions.
- 4. Using the low frequency small signal model for a CE transistor, explain the physical meaning of the terms used. Draw the hybrid π equivalent of a transistor.
- Sketch and explain the cross-section of an N-channel enhancement and depletion MOSFET. Draw the static drain characteristic and transfer characteristic curves for N-channel MOSFET.
- 6. Explain the operation of a UJT as a switch. Describe UJT relaxation oscillator and deduce expression for time period of oscillation.
- 7. Describe the construction and working of SCR. What do you infer from the characteristics?
- 8. Explain the characteristic of photo transistor. Mention its applications.

R-19

Code: 2305/R

Faculty of Science

B. Sc (Electronics) I-Year, CBCS -II Semester Regular Examinations -January, 2021 PAPER: Electronic Devices

Time: 2 Hours Max Marks: 80

I. Answer any Four of the following questions

(4x20=80 Marks)

- 1. Explain V-I characteristics of Zener diode. How it acts as voltage regulator?
- 2. Explain the construction and working of varactor diode. Mention its applications.
- 3. Explain the CB configuration of transistor. Describe itsoutput characteristics.
- 4. Draw the Common Emitter (CE) and Common Collector (CC) hybrid equivalent circuits and write the equations.
- 5. Explain the construction and working of enhancement and depletion modes of MOSFET.
- 6. Describe the construction of UJT. Explain its function as relaxation oscillator.
- 7. escribe the construction and working of Silicon Controlled Rectifier (SCR).
- 8. Explain the construction and working of Light Dependent Resistor (LDR) along with its characteristics.
